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Interfacial Widths of Conjugated Polymer Bilayers

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There is substantial challenge in being able to predict the bulk behavior of organic semiconductors on the basis of their molecular connectivity and composition.1 Because of the weak intermolecular forces between structural units in comparison with inorganic counterparts, there is a strong dependence on processing history and therefore multiple morphologies, each with its own set of properties, can be obtained. Even more poorly understood are interfacial structures and their properties, either adjacent to metal electrodes or between different organic layers, despite their importance in regulating the overall performance of optoelectronic devices.2

It has been shown in polymer light-emitting diodes (PLEDs) that the introduction of a conjugated polyelectrolyte (CPE)3 thin film between the electroluminescent layer and the cathode can be used to reduce the barrier to electron injection from environmentally stable cathodes such as Al or Au.4 The interfaces in these devices have not been extensively studied yet are critical in mediating charge/exciton transport between layers.5 Transmission electron microscopy (TEM) has been successfully used to characterize CPE/neutral conjugated polymer interfaces6 and has shown that only materials cast from solvents of opposite polarity yield sharp interfaces and well-developed bilayer structures. However, quantitative measurements of the interfacial width [i.e., the root-mean-square (rms) width of the laterally averaged physical roughness and the chemical composition gradient normal to the interface] are difficult with TEM, and the interface could only be characterized as being ∼2 nm in width. Possible tools for high-precision characterization include neutron reflectivity7 and X-ray reflectivity,8 but these methods require deuteration of at least one component or suffer from low contrast,9,10 respectively.

In this communication, we report high-precision measurements of organic/organic interfacial widths in CPE-containing model bilayers that are nearly isostructural to those successfully used for improving electron injection into PLEDs, as shown in Figure 1. We utilized resonant soft X-ray reflectivity (RSoXR), a method suitable for quantitative interface characterization that has high intrinsic material contrast for most polymer pairs.10,11 In reflectivity, the partial interference pattern, the width of the various interfaces can be inferred. PFN’X− [X = Br−, tetrakis(imidazolyl)borate (BIm4−)] was chosen as the CPE (see Figure 1 for chemical structures).12 Bilayers were prepared by first casting an ∼80 nm thick poly[2-methoxy-5-(2’-ethylhexyloxy)-p-phenylene vinylene] (MEH-PPV) layer from toluene on oxide-covered silicon substrates. Casting of MEH-PPV was followed by spin-casting of an ∼20 nm thick PFN’X− layer from methanol. Some bilayers were created by casting atop a MEH-PPV layer that was previously thermally annealed at 240 °C. A bilayer structure was also heated to 240 °C for comparison. Finally, single MEH-PPV layers were also prepared to provide a reference for the initial surface roughness.

RSoXR data were acquired at beamline 6.3.2 at the Advanced Light Source (ALS) in Berkeley, CA,13 following previously established protocols that avoid radiation damage.10 Figure 2 presents plots of reflectance versus q obtained at 270 eV and their fits for the MEH-PPV reference layers. For the as-cast MEH-PPV surface, the fit yielded a Gaussian rms roughness of ∼0.56 nm (integrated over a sample area of ∼80 µm × 80 µm); the surface is therefore very sharp and smooth. In contrast, fits for the thermally annealed MEH-PPV yielded an rms surface roughness of ∼1.7 nm, providing a rougher initial surface than the as-cast films. Examination of the MEH-PPV surface topography

Figure 1. (left) Molecular structure of PFN’X−. (right) Nominal thin-film test structures.

Figure 2. Reflectance of single as-cast and annealed MEH-PPV layers.

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smooth out the interface. The PFN+Br/MEH-PPV surface. This clearly demonstrates that casting does not increase the PFN+Br/MEH-PPV bilayer is 2.0 nm, an increase of 0.3 nm relative to the preannealed procedure. The interfacial roughness for the PFN+X− and MEH-PPV layer thicknesses (in nm) as measured with RSoXR.

Table 1. RSoXR Results from Fits

<table>
<thead>
<tr>
<th>Sample</th>
<th>Surface Width (nm)</th>
<th>Average (nm)</th>
<th>Interfacial Width (nm)</th>
<th>Average (nm)</th>
</tr>
</thead>
<tbody>
<tr>
<td>As-cast MEH-PPV</td>
<td>Spot1: 0.60</td>
<td>0.60</td>
<td>N/A</td>
<td></td>
</tr>
<tr>
<td>PFN+Br+/MEH-PPV</td>
<td>Spot1: 0.67</td>
<td>0.65</td>
<td>0.85</td>
<td>0.80</td>
</tr>
<tr>
<td>PFN+Br+/MEH-PPV</td>
<td>Spot2: 0.63</td>
<td>0.74</td>
<td>0.79</td>
<td>0.82</td>
</tr>
<tr>
<td>Annealed PFN+Br+/MEH-PPV</td>
<td>Spot1: 1.7</td>
<td>1.7</td>
<td>N/A</td>
<td></td>
</tr>
<tr>
<td>Annealed PFN+Br+/MEH-PPV</td>
<td>Spot2: 1.7</td>
<td>1.7</td>
<td>N/A</td>
<td></td>
</tr>
</tbody>
</table>

by atomic force microscopy (AFM) provided rms results that are consistent with those obtained by RSoXR (see the Supporting Information).

RSoXR plots of the two CPE/MEH-PPV bilayers on as-cast MEH-PPV are presented in Figure 3, along with data for a bilayer of PFN+Br− cast atop annealed MEH-PPV. Modulations of the Kiessig fringes reminiscent of interference beats are readily observable for all of the bilayers. These modulations are distinct from the fringes observable in Figure 2 and directly indicate sensitivity to the buried organic/organic interface. Qualitative differences depending on whether the MEH-PPV was thermally annealed can also be readily observed. Because of the larger roughness of the interface in the former sample, the beating is suppressed. Through fits as shown in Figure 3, quantitative values for the widths of the surface and the CPE/polymer interface were extracted, and the results are summarized in Table 1. As-cast bilayers have smooth interfaces with average rms widths of 0.80 and 0.82 nm for PFN+Br−/MEH-PPV and PFN+Br−/MEH-PPV, respectively. The CPE/MEH-PPV interfacial widths are only slightly larger than the surface roughness of the MEH-PPV reference layer.

As evidenced even in the raw data in Figures 2 and 3, the surface and interfacial widths can be greatly affected by the sample preparation procedure. The interfacial roughness for the PFN+Br−/annealed MEH-PPV bilayer is 2.0 nm, an increase of 0.5 nm relative to the preannealed MEH-PPV surface. This clearly demonstrates that casting does not smooth out the interface. The PFN+Br+/MEH-PPV bilayer that was thermally annealed (included only for illustrating RSoXR) shows a markedly different reflectance profile because of an interfacial width of 5.9 nm. The increased widths observed for the as-cast bilayers relative to that of the starting MEH-PPV surface could be due to roughening (lack of smoothness) or chemical interdiffusion (lack of sharpness). However, AFM (see the Supporting Information) shows dominating lateral structures >10 nm in size for the initial MEH-PPV surface. This is significantly larger than the measured interfacial width. Consequently, in conjunction with the observation that casting on rough MEH-PPV does not result in smoother interfaces, it is highly likely that the physical roughness of the interface does not decrease for the as-cast films. Since these as-cast samples with a very thin top layer do not have frozen-in capillary waves, the chemical interdiffusion and physical roughness add quadrature to the rms width; the upper limit for the chemical interdiffusion is thus (0.81^2 − 0.56^2)0.5 = 0.59 nm.

In conclusion, we have shown that the interfaces of differentially cast CPE/MEH-PPV bilayers can be very smooth and sharp. This demonstrates with high precision that the MEH-PPV layer is not much disturbed by casting the CPE layer from a polar solvent. The chemical interdiffusion due to casting is limited to less than 0.6 nm, as the increase in width observed might be partially due to roughening. The interface created is thus nearly “molecularly” sharp. These results establish a baseline for understanding the role of interfacial structure in determining the performance of CPE-based PLEDs. More broadly, we anticipate further applications of RSoXR in achieving a deeper understanding of other multilayer organic optoelectronic devices, including multilayer photovoltaic devices.

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Supporting Information Available: Synthetic and device-fabrication procedures, RSoXR data acquisition and analysis, and AFM images. This material is available free of charge via the Internet at http://pubs.acs.org.

References


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